

Anomalous Proximity Effect in Underdoped $\text{YBa}_2\text{Cu}_3\text{O}_{6+x}$ Josephson Junctions

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Abstract

Josephson junctions were photogenerated in underdoped thin films of the $\text{YBa}_2\text{Cu}_3\text{O}_{6+x}$ family using a near-field scanning optical microscope. The observation of the Josephson effect for separations as large as 100 nm between two wires indicates the existence of an anomalously large proximity effect and show that the underdoped insulating material in the gap of the junction is readily perturbed into the superconducting state. The critical current of the junctions was found to be consistent with the conventional Josephson relationship. This result constrains the applicability of $\text{SO}(5)$ theory to explain the phase diagram of high critical temperature superconductors.

74.50.+r, 74.80.Fp, 74.72.Bk, 74.76.Bz

Despite being among the most intensely studied condensed-matter systems, high temperature superconductors (HTS) have resisted a microscopic understanding [1]. They are strongly anisotropic highly correlated electronic systems, showing anomalous characteristics in both the superconducting and non-superconducting phases. In particular, the nature of the transition between the low carrier concentration insulating antiferromagnetic (AF) phase and the high carrier concentration metallic and superconducting (SC) phase is not known and it is believed to be key to uncovering the superconducting mechanism in these materials. The quest to gain a better understanding of these issues is reflected in extensive experimental and theoretical work [1–8]. Recently an elegant theory, based on $SO(5)$ group symmetry [2], proposed a basic framework to explain the HTS phase diagram. A five component superspin was introduced with two of its components associated with the order parameter in a d -wave SC state and the other three identified with the order parameter of the AF phase. In this theory, the quantum phase transition between the AF and SC phases corresponds to a change in the orientation of the superspin in this five-dimensional space. A different approach for describing the rich phase diagram of the HTS materials postulates superconducting pairing at a temperature T^* well above the superconducting critical temperature T_c . The low stiffness of the superconducting order parameter, due to their large penetration length [3], leads to fluctuations in the phase of the order parameter [4,5] between T^* and T_c . It is not until phase coherence is achieved at T_c that superconductivity is established in the material. The overall behavior of the superconductor between T^* and T_c resembles that of a Kosterlitz-Thouless transition in conventional two-dimensional superconductors.

The electronic nature of the underdoped system near the superconducting state is significantly different than the normal state found in conventional superconductors. Consequently, the experimental manifestation of superconductivity may also be expected to differ. Within the framework of the $SO(5)$ theory, Demler *et al.* [6] have predicted that the current-phase relationship in the coupling between two HTS separated by a thin AF layer (a *SAS* junction) is modified from the Josephson relation $I_J = I_o \sin \phi$, with ϕ the superconducting phase difference across the junction [9,10]. If the thickness of the junction $d < d_c = \pi \xi_A$ the AF

material becomes a superconductor for $\phi < \phi_c$ and “conventional” Josephson effect occurs only for $\phi > \phi_c$, where ξ_A represents a new superconducting correlation length in the AF phase [6] and $\phi_c \sim \pi\sqrt{1 - (\frac{d}{d_c})^2}$ [7].

This difference in the current-phase relationship of a *SAS* junction leads to different behavior of Josephson junctions, as investigated by den Hertog and co-workers [7]. In particular, they predicted that the critical current of the junctions $I_c(H)$ would show a linear decrease with an applied magnetic field around $H = 0$ [7]; i. e., a cusp in the $I_c(H)$ dependence, instead of the quadratic low field behavior found in conventional junctions. We are not aware of an analogous prediction within the framework of the fluctuating-phase model.

Both the fluctuating-phase approach and the SO(5) theory share the possibility of a large proximity effect when the material separating the HTS wires is the insulating HTS precursor. These considerations suggest that Josephson junctions may be made by separating HTS with a relatively thick layer of the precursor material [3,6].

We exploit the capability of locally photodoping an insulating $R\text{Ba}_2\text{Cu}_3\text{O}_{6+x}$ material (with R a rare earth), to induce superconducting wires separated by a non-superconducting region [11]. The flexibility provided by our near-field scanning optical microscope (NSOM) allows us to vary the gap between the $w \sim 150$ nm wide superconducting wires.

The samples under consideration are *c*-axis oriented thin films. One is a 180 nm thick $\text{GdBa}_2\text{Cu}_3\text{O}_{6+x}$ film grown on (100) MgO substrates by dc-magnetron sputtering. The other sample is a 120 nm thick $\text{YBa}_2\text{Cu}_3\text{O}_{6+x}$ (YBCO) film deposited on a SrTiO_3 substrate by laser ablation. The as-grown films show good physical properties with linear temperature dependence of the dc resistivity. Their critical temperatures, determined by ac-susceptibility, were $T_c = 89.4$ K and 89.2 K, respectively. To place the samples in the insulating side of the Metal-Insulator transition (MI), their oxygen content was adjusted to $x \sim 0.4$ [12]. After reduction, the resistivity of the samples at 4 K was found to be $\rho \sim 6$ m Ω cm. The results obtained in both samples are very similar and we will concentrate on the data obtained in the YBCO film.

The film was mounted on the insert of a continuous-flow He cryostat and photodoped with an Al-coated 60 nm aperture NSOM probe [11]. Light from either a 3 mW He-Ne or a 1 mW, $\lambda = 1.55 \mu\text{m}$, InGaAsP laser was coupled into the inputs of a 50/50 2×2 optical fiber coupler. One of the outputs of the coupler was connected to the NSOM probe, while the other was used to monitor the laser stability. Photogeneration was accomplished by illuminating with the 1.96 eV light from the He-Ne laser, which is close to the maximum of the photodoping efficiency [14]. The photoinduced changes in the sample were detected by imaging the reflectance variations at $\lambda = 1.55 \mu\text{m}$ with the InGaAsP laser. The reflected light was collected in the far field with conventional optics [13]. The InGaAsP laser was chosen because $\lambda = 1.55 \mu\text{m}$ radiation provides the maximum change in reflectivity when crossing the MI transition [15] and it does not induce any further photogeneration [11,14]. Photon fluxes per unit time were estimated to be $Q_{exc} \sim 8.6 \times 10^{20}$ photons/(cm² s) and $Q_{ref} \sim 3.2 \times 10^{20}$ photons/(cm²s) for photoexcitation and reflectivity measurements, respectively. All the measurements involving the NSOM were performed at room temperature. When necessary to prevent the superconducting wires from decaying by e - h recombination [11,14,16], the NSOM head was removed, the cryostat closed and pumped to 10^{-6} Torr and the sample cooled to 200 K in less than 15 min [17]. It is well documented [11,16] that below 250 K the photoinduced state is metastable.

Typical NSOM reflectance scans are shown in Fig. 1. The wires were defined and the scans obtained as described in Ref. [11]. Fig. 1 shows that the reflectance and T_c of the wires increase with the duration of the photogeneration. These results are explained by the photoinduced local increase of free holes in the CuO planes of YBCO [11,14,16].

Josephson junctions were defined by photogenerating a wire and leaving an unilluminated gap along its length, as described in Ref. [11]. A typical example of these junctions is illustrated in Fig. 2a. We determine the gap d between the superconducting wires from the reflectance data shown in Fig. 1. We define d as the range where the reflectance is lower than that corresponding to the wire in Fig. 1b, which has a $T_c \sim 4$ K. From this definition of d the part of the junction between points **b** of Fig. 2b is insulating in character. The

separation between these points is ~ 90 nm. Because of the finite resolution of the NSOM this procedure gives a lower limit of the thickness of the barrier between the wires. After defining an identical junction and cooling the system to 4 K, $I - V$ characteristics were obtained, as shown in the inset of Fig. 2a. The zero dissipation region shows the existence of Josephson effect between the two wires [9]. The rounding of the I-V curves is understood in terms of thermal fluctuations in the Josephson junction [9].

The observation of the Josephson effect for a separation between superconducting wires much greater than the coherence length in the superconducting state ($\xi_o \sim 1$ nm [1]) is one of the main results of this paper. This “colossal” proximity effect is inexplicable even if it is assumed that the material in the gap is metallic. In this case, the coherence length for the metal in the clean limit is $\zeta \simeq \frac{\hbar v_f}{2\pi k_B T}$, where v_f is its Fermi velocity [9,10]. For reasonable values of v_F , ζ turns out to be the same order of magnitude as ξ_o . From these considerations we conclude that conventional proximity effect cannot explain our results and that the insulating material in the junctions exhibits an anomalously large proximity effect. Further evidence that a superconducting state is induced in the gap material is provided by the value of the critical current of the junction. For the $d = 45$ nm junction, $I_c = 2.6\mu\text{A}$, very close to the measured value of $I_c = 11.5\mu\text{A}$ for the wire of Fig. 1a.

As can be seen in the inset of Fig. 2b, $I_c R_N$ ($R_N = \frac{dV}{dI}|_{I=7\mu\text{A}}$ is the shunt resistance of the junction) is nearly independent of d for $d < 110$ nm. This fact has implications for both SO(5) theory and the fluctuating-phase models: When the existence of free vortices is used to explain the lack of phase coherence in the gap material, $I_c R_N \propto \exp(-d/2\zeta_g)$ is expected, where $\zeta_g \simeq \xi_o \exp(T_\Theta/T)$ is the correlation length for phase fluctuations, and T_Θ is the phase stiffness expressed in temperature units [4]. From the observed weak d dependence of $I_c R_N$ when $d \lesssim 100$ nm, it follows that $\zeta_g \gg 90$ nm and $T_\Theta \gtrsim 30$ K. As the separation between wires increases, however, a collapse in the phase coherence is observed and no Josephson effect is observed. In the SO(5) theory $I_c \propto \exp(-d/\xi_A)$ implying that the correlation length satisfies $\xi_A \gg d$ [6,9]. It is possible to have strong d dependence in both I_c and R_N , that cancel each other, as in the case in a tunnel Josephson junction in conventional supercon-

ductors. This possibility is ruled out, however, by the measured temperature dependence of the resistance of the non-superconducting material. R_N is temperature independent *if the Josephson effect is observed*. Once the separation between the wires is large enough that the Josephson effect is absent, an insulating-like response is observed for the unphotodoped material. The difference found in the temperature dependence of the non-superconducting material for different junctions is attributable to their difference in length, as shown in Fig. 3. The minor deviations between the data sets might be associated with the specific geometric details of the path followed by the transport current in each case, together with the definition of d .

The observed behavior of these Josephson junctions may be expected if the gap material *is thermodynamically very close to the superconducting state* and the presence of the superconducting leads quenches the superconducting phase fluctuations in the gap material. The induction of superconductivity in the non-superconducting material is a feature of both the SO(5) theory [2,6] and the fluctuating phase models [3]. More generally, as discussed in Ref. [6], the only ingredient necessary to obtain such a large correlation length is the close proximity to a second order quantum phase transition.

One observation of this experiment appears to be in contradiction with the SO(5) theory. Since the observed behavior of $I_c R_N$ implies that $\xi_A \gg d$ our experiments correspond to the case analyzed in Ref. [6], *if the material between the superconducting wires is in the AF phase*. In this scenario, $I_c(H)$ should show a cusp for $H \rightarrow 0$ [7]. The cusp is expected even for situations where the critical current is not uniform along the width of the junction, as expected for junctions made by our technique [18]. The results obtained for small magnetic fields are shown in Fig. 4. The figure shows that for $H \rightarrow 0$, $I_c(H) \not\propto |H|$, but is better described by a quadratic dependence. Also shown in the figure is the calculated $I_c(H)$ using the model from Ref. [7]. The experimental value of $H = 135$ Oe for the first flux-quantum trapped in the junction, obtained from the Fraunhofer-like dependence of $I_c(H)$, was used in the calculation. As shown in the figure, *the agreement between the experimental data and the calculation is reasonable only if $d \sim d_c$* , in clear contradiction with the $\xi_A \gg d$ conclusion

obtained from Fig. 2b.

The effects observed in the junctions are independent of the sequence in which the magnetic field is applied. The same results are observed if the sample is cooled through the superconducting transition in zero magnetic field, and then the field is brought up to the desired value (zero-field cooled experiment); or if the sample is cooled in the desired field (field-cooled experiment). Although the lower critical field in these underdoped HTS materials is expected to be very small, no difference is found since $w < \lambda_p \sim 500$ nm [19], where λ_p is the penetration length in the superconductor. In this condition size effects are very important and it is energetically unfavorable to induce vortices in the superconducting wires.

The results described in this report show that the local combination of superconducting and insulating materials, obtained by photodoping insulating YBCO with a NSOM probe, provides an ideal opportunity to examine the validity of the different models of high critical temperature superconductors. The observation of the Josephson effect for separations $d \sim 100$ nm cannot be explained by the conventional proximity effect. We conclude that the material between the superconducting wires, although insulating, must be very close to a superconducting phase transition since superconductivity with a large phase coherence length can be induced in it. We have also been able to restrict the margin of applicability of the SO(5) theory to explain the phase diagram of HTS. In view of the observed results and with the available models, only the existence of an AF and SC phases separated by a quantum disordered phase remains compatible with the theory. Although our results seem to be in qualitative agreement with fluctuating-phase models, more theoretical work is required to obtain the characteristics of the Josephson effect within this picture.

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- [17] The recombination time of different samples at room temperature has been found to vary between 30 min and more than a day. Although the large dispersion in recombination time is not understood, it is known that sample morphology, growth methods, and sample thickness, among other factors, affect it. In our case, the recombination time for the YBCO sample was ~ 10 hrs, while the $\text{GdBa}_2\text{Cu}_3\text{O}_{6.4}$ sample had a recombination time ~ 50 min.
- [18] In this case, $I_c(H) = \frac{1}{L} \int_0^L I_c(\phi(x)) dx$, where ϕ is position dependent through the gauge-invariant superconducting phase difference across the junction and the spatial dependence induced by the particular details of the geometry of the junction. A numerical integration yields $I_c(H) \propto |H|$. This result is to be expected, since it is obtained by adding a heavily weighted “anomalous” junction with a lightly weighted conventional one.
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FIGURES

FIG. 1. (color) Reflectance of photodoped wires. The wires were photodoped for **(a)** 5000 s, **(b)** 1300 s, **(c)** 800 s, and **(d)** 600 s. The number in each $1.24 \times 0.64 \mu\text{m}^2$ image indicates the percentile increase in reflectance of the wire (at $\lambda = 1.55\mu\text{m}$) with respect to the unphotodoped material. The coordinate system used throughout the paper is shown in **(a)**. The inset shows the temperature dependence of the resistance for each wire, normalized by the value of the resistance at 15 K.

FIG. 2. (color) Josephson effect in photogenerated junctions. **(a)** $1.24 \times 0.64 \mu\text{m}^2$ reflectance data of a photogenerated junction, normalized to the reflectance of the unphotodoped material. The gap in the illuminated region was $D = 220 \text{ nm}$. The inset shows the $I - V$ characteristic curve. **(b)** Line cut along the dotted line in **(a)**. The letters represent the different intensities observed in Fig. 1. The inset shows the value of $I_c R_N$ for junctions fabricated with different d .

FIG. 3. Temperature dependence of the resistance of the junctions that do not show Josephson effect. The inset shows the data normalized by the separation between the superconducting wires.

FIG. 4. Magnetic field dependence of the critical current close to $H = 0 \text{ Oe}$. For comparison, $I_c(H)$ obtained from Ref. [7] for different values of $\delta = \frac{d}{d_c}$ is included. In all cases the curves have been normalized for $H = 0 \text{ Oe}$.